4-Bit Magnitude Comparator

The TC74HC85A is a high speed CMOS 4-BIT MAGNITUDE COMPARATOR fabricated with silicon gate C^2MOS technology.

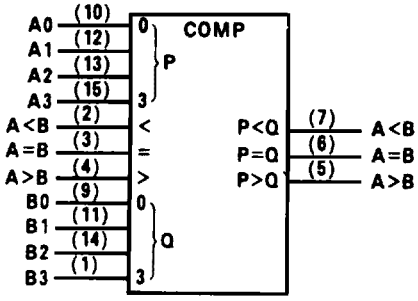
It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The TC74HC85A compares two 4-bit words applied to inputs A0 - A3 and B0 - B3, and provides a high voltage level on one of three outputs: A > B, A < B, or A = B.

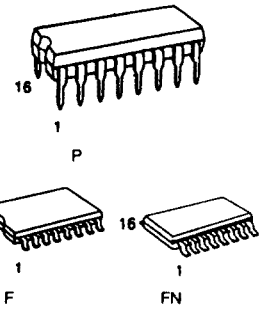
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

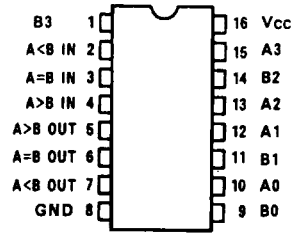
Features

- High Speed: t_{PD} = 22ns(Typ.) at V_{CC} = 5V
- Low Power Dissipation: I_{CC} = 2μA(Max.) at Ta = 25°C
- High Noise Immunity: $V_{NIH} = V_{NIL}$ = 28%V_{CC}(Min.)
- Output Drive Capability: 10 LSTTL Loads
- Symmetrical Output Impedance: $|I_{OH}| = I_{OL}$ = 4mA(Min.)
- Balanced Propagation Delays: $t_{pLH} = t_{pHL}$
- Wide Operating Voltage Range: V_{CC}(opr) = 2V ~ 6V
- Pin and Function Compatible with 74LS85



IEC Logic Symbol





Pin Assignment

Truth Table

Comparing Inputs				Cascading Inputs			Outputs		
				A > B	A < B	A = B	A > B	A < B	A = B
A3>B3	X	X	X	X	X	X	H	L	L
A3 = B3	A2 > B2	X	X	X	X	X	H	L	L
A3 = B3	A2 = B2	A1 > B1	X	X	X	X	H	L	L
A3 = B3	A2 = B2	A2 = B1	A0 > B0	X	X	X	H	L	L
A3 = B3, A2 = B2, A1 = B1, A0 = B0				L	L	L	H	H	L
				X	X	H	L	L	H
				L	H	L	L	H	L
				H	L	L	H	L	L
				H	H	L	L	L	L
A3 = B3	A2 = B2	A2 = B1	A0 < B0	X	X	X	L	H	L
A3 = B3	A2 = B2	A1 < B1	X	X	X	X	L	H	L
A3 = B3	A2 < B2	X	X	X	X	X	L	H	L
A3 < B3	X	X	X	X	X	X	L	H	L

X: Don't Care

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Supply Voltage Range	V_{CC}	-0.5 ~ 7	V
DC Input Voltage	V_{IN}	-0.5 ~ V_{CC} + 0.5	V
DC Output Voltage	V_{OUT}	-0.5 ~ V_{CC} + 0.5	V
Input Diode Current	I_{IK}	±20	mA
Output Diode Current	I_{OK}	±20	mA
DC Output Current	I_{OUT}	±25	mA
DC V_{CC}/Ground Current	I_{CC}	±50	mA
Power Dissipation	P_D	500(DIP)*/180(MFP)	mW
Storage Temperature	T_{stg}	-65 ~ 150	°C
Lead Temperature 10sec	T_L	300	°C

*500mW in the range of Ta = -40°C ~ 65°C. From Ta = 65°C to 85°C a derating factor of -10mW/°C shall be applied until 300mW.

Recommended Operating Conditions

Parameter	Symbol	Value	Unit
Supply Voltage	V_{CC}	2 ~ 6	V
Input Voltage	V_{IN}	0 ~ V_{CC}	V
Output Voltage	V_{OUT}	0 ~ V_{CC}	V
Operating Temperature	T_{opr}	-40 ~ 85	°C
Input Rise and Fall Time	t_r, t_f	0 ~ 1000(V_{CC} = 2.0V) 0 ~ 500(V_{CC} = 4.5V) 0 ~ 400(V_{CC} = 6.0V)	ns

DC Electrical Characteristics

Parameter	Symbol	Test Condition			Ta = 25°C			Ta = -40 ~ 85°C		Unit
				V_{CC}	Min	Typ.	Max.	Min.	Max.	
High-Level Input Voltage	V_{IH}	–		2.0 4.5 6.0	1.5 3.15 4.2	– – –	– – –	1.5 3.15 4.2	– – –	V
Low-Level Input Voltage	V_{IL}	–		2.0 4.5 6.0	– – –	– – –	0.5 1.35 1.8	– – –	0.5 1.35 1.8	V
High-Level Output Voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = -20μA	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0	– – –	1.9 4.4 5.9	– – –	V
			I_{OH} = -4 mA I_{OH} = -5.2mA	4.5 6.0	4.18 5.68	4.31 5.80	– –	4.13 5.63	– –	
Low-Level Output Voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 20μA	2.0 4.5 6.0	– – –	0.0 0.0 0.0	0.1 0.1 0.1	– – –	0.1 0.1 0.1	V
			I_{OL} = 4 mA I_{OL} = 5.2mA	4.5 6.0	– –	0.17 0.18	0.26 0.26	– –	0.33 0.33	
Input Leakage Current	I_{IN}	V_{IN} = V_{CC} or GND		6.0	–	–	±0.1	–	±1.0	μA
Quiescent Supply Current	I_{CC}	V_{IN} = V_{CC} or GND		6.0	–	–	4.0	–	40.0	

AC Electrical Characteristics (C_L = 15pF, V_{CC} = 5V, Ta = 25°C)

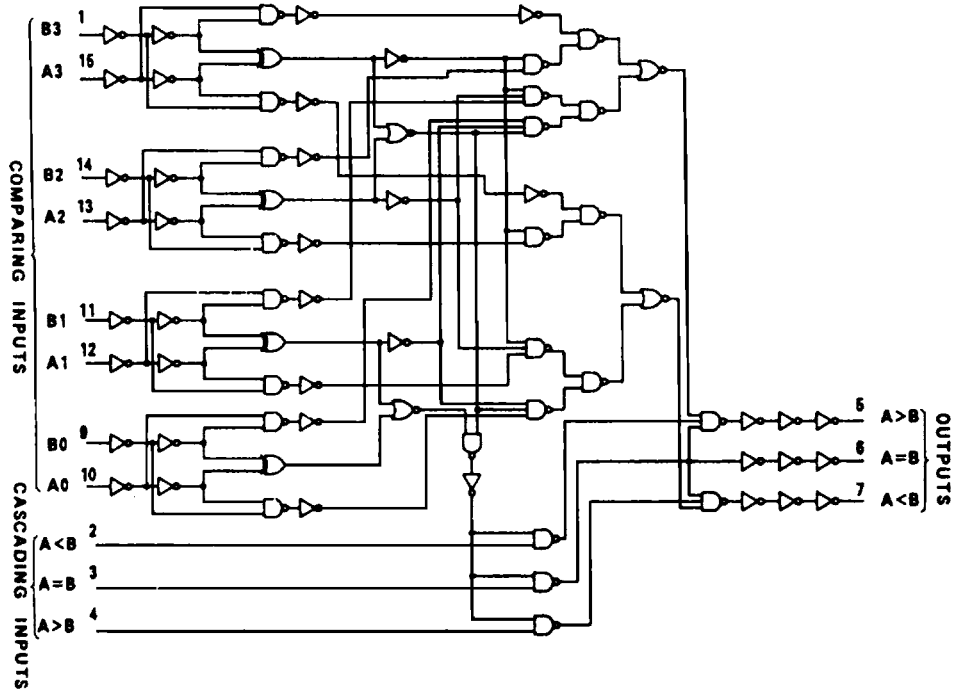
Parameter	Symbol	Test Conditon	Min.	Typ.	Max.	Unit
Output Transition Time	t_{TLH} t_{THL}	–	–	4	8	ns
Propagation Delay Time (A, B-OUT)	t_{pLH} t_{pHL}	–	–	22	34	
Propagation Delay Time (CASCADE-OUT)	t_{pLH} t_{pHL}	–	–	10	18	

AC Electrical Characteristics (C_L = 50pF, Input $t_r = t_f$ = 6ns)

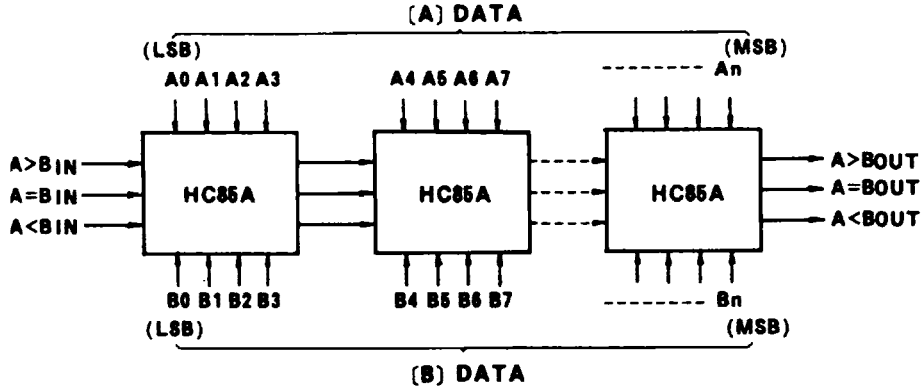
Parameter	Symbol	Test Condition		Ta = 25°C			Ta = -40 ~ 85°C		Unit
			V_{CC}	Min	Typ.	Max.	Min.	Max.	
Output Transition Time	t_{TLH} t_{THL}	–	2.0	–	30	75	–	95	ns
			4.5	–	8	15	–	19	
			6.0	–	7	13	–	16	
Propagation Delay Time (A,B-OUT)	t_{pLH} t_{pHL}	–	2.0	–	90	195	–	245	
			4.5	–	26	39	–	49	
			6.0	–	22	33	–	42	
Propagation Delay Time CASCADE-OUT)	t_{pLH} t_{pHL}	–	2.0	–	40	110	–	140	
			4.5	–	13	22	–	28	
			6.0	–	11	19	–	24	
Input Capacitance	C_{IN}	–		–	5	10	–	10	pF
Power Dissipation Capacitance	C_{PD}(1)	–		–	25	–	–	–	

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:

$I_{CC(opr)} = C_{PD} \bullet V_{CC} \bullet f_{IN} + I_{CC}$



Logic Diagram



Typical Application

Comparing Input	Cascading Inputs			Output		
	A > B	A = B	A < B	A > B	A = B	A < B
[A] > [B]	X	X	X	H	L	L
[A] = [B]	H	L	L	H	L	L
	X	H	X	L	H	L
	L	L	H	L	L	H
[A] < [B]	X	X	X	L	L	H

X: Don't Care